## TIP131, TIP132 (NPN), TIP137 (PNP)

**Preferred Devices** 

# **Darlington Complementary Silicon Power Transistors**

Designed for general-purpose amplifier and low-speed switching applications.

#### **Features**

• High DC Current Gain -

$$h_{FE} = 2500 \text{ (Typ)} @ I_{C}$$
  
= 4.0 Adc

• Collector-Emitter Sustaining Voltage - @ 30 mAdc

• Low Collector-Emitter Saturation Voltage -

$$V_{CE(sat)} = 2.0 \text{ Vdc (Max)} @ I_C = 4.0 \text{ Adc}$$
  
= 3.0 Vdc (Max) @  $I_C = 6.0 \text{ Adc}$ 

- Monolithic Construction with Built-In Base-Emitter Shunt Resistors
- Pb-Free Packages are Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	TIP131	TIP132 TIP137	Unit
Collector-Emitter Voltage	$V_{CEO}$	80	100	Vdc
Collector-Base Voltage	V <sub>CB</sub>	80 100		Vdc
Emitter-Base Voltage	V <sub>EB</sub>	5.0		Vdc
Collector Current - Continuous Peak	I <sub>C</sub>	8.0 12		Adc
Base Current	I <sub>B</sub>	300		mAdc
Total Power Dissipation @ T <sub>C</sub> = 25°C	$P_{D}$	70		W
Total Power Dissipation @ T <sub>A</sub> = 25°C	P <sub>D</sub>	2.0		W
Operating and Storage Junction, Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	65 to +150		°C

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.78	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	63.5	°C/W

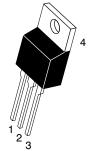
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



### ON Semiconductor®

http://onsemi.com

### DARLINGTON 8 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 80-100 VOLTS, 70 WATTS



### MARKING DIAGRAM

AB
1A TIP13xG
AYWW

TO-220AB CASE 221A STYLE 1

TIP13x = Device Code x = 1, 2, or 7

A = Assembly Location

Y = Year WW = Work Week G = Pb-Free Package

#### **ORDERING INFORMATION**

Device	Package	Shipping
TIP131	TO-220	50 Units/Rail
TIP131G	TO-220 (Pb-Free)	50 Units/Rail
TIP132	TO-220	50 Units/Rail
TIP132G	TO-220 (Pb-Free)	50 Units/Rail
TIP137	TO-220	50 Units/Rail
TIP137G	TO-220 (Pb-Free)	50 Units/Rail

**Preferred** devices are recommended choices for future use and best overall value.

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<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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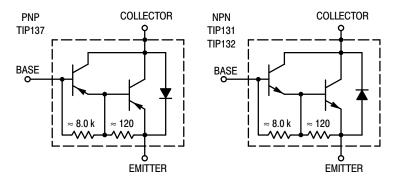


Figure 1. Darlington Circuit Schematic

### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS		-			
Collector-Emitter Sustaining Voltage (Note 1) (I <sub>C</sub> = 30 mAdc, I <sub>B</sub> = 0)	TIP131 TIP132, TIP137	V <sub>CEO(sus)</sub>	80 100	- -	Vdc
Collector Cutoff Current $(V_{CE} = 40 \text{ Vdc}, I_B = 0)$ $(V_{CE} = 50 \text{ Vdc}, I_B = 0)$	TIP131 TIP132, TIP137	I <sub>CEO</sub>	- -	0.5 0.5	mAdc
Collector Cutoff Current $(V_{CB} = 80 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$	TIP131 TIP132, TIP137	I <sub>CBO</sub>	- -	0.2 0.2	mAdc
Emitter Cutoff Current $(V_{BE} = 5.0 \text{ Vdc}, I_C = 0)$		I <sub>EBO</sub>	-	5.0	mAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain $ \begin{aligned} &(I_C=1.0 \text{ Adc, V}_{CE}=4.0 \text{ Vdc}) \\ &(I_C=4.0 \text{ Adc, V}_{CE}=4.0 \text{ Vdc}) \end{aligned} $		h <sub>FE</sub>	500 1000	- 15000	-
Collector-Emitter Saturation Voltage ( $I_C = 4.0$ Adc, $I_B = 16$ mAdc) ( $I_C = 6.0$ Adc, $I_B = 30$ mAdc)		V <sub>CE(sat)</sub>	- -	2.0 3.0	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = 4.0 Adc, V <sub>CE</sub> = 4.0 Vdc)		V <sub>BE(on)</sub>	-	2.5	Vdc

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%.

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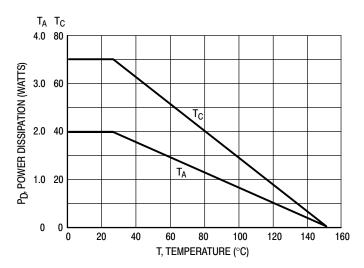


Figure 2. Power Derating

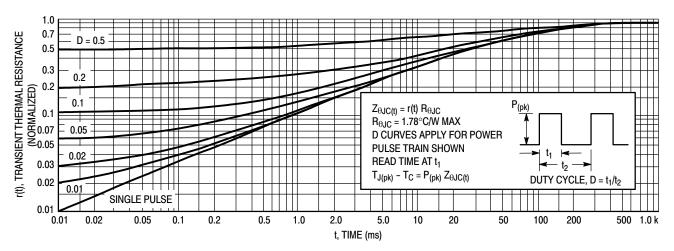
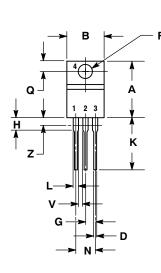


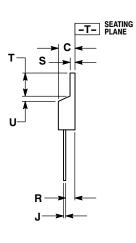
Figure 3. Thermal Response

### TIP131, TIP132 (NPN), TIP137 (PNP)

### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AE** 





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

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